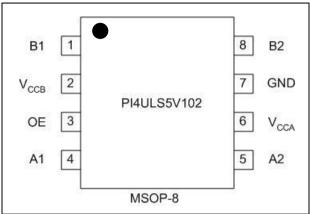




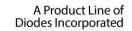
# **Pin Configuration**



## **Pin Description**

Pin Name	Description
B1, B2	Input/output B. Referenced to V <sub>CCB</sub> .
GND	Ground.
$V_{CCA}$	A port supply voltage. 1.2 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub> .
A1, A2	Input/output A. Referenced to V <sub>CCA</sub> .
OE	3-State output. Pull OE low to place all outputs in 3-state mode. Referenced to V <sub>CCA</sub> .
V <sub>CCB</sub>	B port supply voltage. $1.65 \text{ V} \leq \text{V}_{\text{CCB}} \leq 5.5 \text{ V}$ .







## Maximum Ratings (1)

	<del>-</del>		Min	Max	Unit
$V_{CCA}$	Supply voltage range		-0.5	4.6	V
$V_{CCB}$	Suppry voltage range		-0.5	6.5	V
$V_{I}$	Input voltage range	A port	-0.5	4.6	V
v <sub>I</sub>	input voltage range	B port	-0.5	6.5	V
$V_{\rm o}$	Voltage range applied to any output in the high-impedance or	A port	-0.5	4.6	V
v <sub>O</sub>	power-off state	B port	-0.5	6.5	V
V	Voltage range applied to any output in the high or low state *2	A port	-0.5	$V_{CCA} + 0.5$	V
$V_{\rm O}$	Voltage range applied to any output in the high of low state	B port	-0.5	$V_{CCB} + 0.5$	V
$I_{IK}$	Input clamp current, V <sub>I</sub> < 0			-50	mA
$I_{OK}$	Output clamp current, V <sub>O</sub> < 0			-50	mA
$I_{O}$	Continuous output current			±50	mA
$I_{O}$	Continuous current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND			±100	mA
$T_{stg}$	Storage temperature range		-65	150	$^{\circ}\mathbb{C}$

<sup>\*1</sup> Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Recommend Operation Conditions (1)(2)

Parameter	Description		V <sub>CCA</sub>	$V_{CCB}$	Min	Max	Unit
$V_{CCA}$	Cumply voltage		-	-	1.2	3.6	V
V <sub>CCB</sub>	Supply voltage		-	-	1.65	5.5	v
W	High level input voltage	Data inputs	1.2V to 3.6V	1.65V to 5.5V	V <sub>CCI</sub> * 0.65 <sup>(3)</sup>	$V_{CCI}$	V
V <sub>IH</sub>	High-level input voltage	OE input	1.2V to 3.6V	1.65V to 5.5V	V <sub>CCA</sub> * 0.7	5.5	v
W	Low lovel imput veltage	Data inputs	1.2V to 3.6V	1.65V to 5.5V	0	V <sub>CCI</sub> * 0.35 <sup>(3)</sup>	V
$V_{\mathrm{IL}}$	Low-level input voltage	OE input	1.2V to 3.6V	1.65V to 5.5V	0	V <sub>CCA</sub> * 0.3	V
V	Voltage range applied to any output in the	A port	1.2V to	1.65V to	0	3.6	V
$V_{0}$	high-impedance or power-off state	B port	3.6V	5.5V	0	5.5	·
		A port inputs	1.2V to 3.6V	1.65V to 5.5V	-	40	
∆t/∆v	Input transition rise or fall rate	B port	1.2V to	1.65V to 3.6V	-	40	ns/V
		inputs	3.6V	4.5V to 5.5V	-	30	
$T_A$	Operating free-air temperature		-	-	-40	85	$^{\circ}$

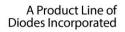
<sup>(1)</sup> The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V<sub>CCI</sub> or both at GND.

<sup>\*2</sup> The value of V<sub>CCA</sub> and V<sub>CCB</sub> are provided in the recommended operating conditions table.

<sup>(2)</sup>  $V_{CCA}$  must be less than or equal to  $V_{CCB}$  and must not exceed 3.6 V.

<sup>(3)</sup>  $V_{CCI}$  is the supply voltage associated with the input port.







# DC Electrical Characteristics (1)(2)

	4	T. 4 C. 1949	<b>T</b> 7	<b>T</b> 7		$T_A = 25^{\circ}C$	!	-40 to	85℃	<b>T</b> T •4
Par	rameter	Test Conditions	$\mathbf{V}_{\mathbf{CCA}}$	$\mathbf{V}_{ ext{CCB}}$	Min	Тур	Max	Min	Max	Unit
			1.2V		1.0	1.1	1.2	-	-	
•	$V_{\mathrm{OHA}}$	$I_{OH} = -20\mu A$	1.4V to 3.6V	-	-	-	-	V <sub>CCA</sub> - 0.4	-	V
,	C.	I - 20 A	1.2V		0.0	0.09	0.4	-	-	V
	$V_{OLA}$	$I_{OL} = 20 \mu A$	1.4V to 3.6V	-	-	-	-	-	0.4	
•	$V_{OHB}$	$I_{OH} = -20 \mu A$	-	1.65V to 5.5V	-	-	-	V <sub>CCB</sub> - 0.4		V
٦	$V_{OLB}$	$I_{OL} = 20 \mu A$	-	1.65V to 5.5V	ı	-	-	-	0.4	V
$I_{I}$	OE	$V_{I} = V_{CCI}$ or GND	1.2 to 3.6V	1.65V to 5.5V	ı	-	±1	-	±2	μΑ
T	A port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 3.6V	0V	0V to 5.5V	1	-	±1	-	±2	4
$I_{ m off}$	B port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 5.5V	0 to 3.6V	0V	-	-	±1	-	±2	μΑ
$I_{OZ}$	A or B port	OE = GND	1.2 to 3.6V	1.65V to 5.5V	-	-	±1	-	±2	μΑ
			1.2V	1.65V to 5.5V	0.0	0.06	5.0	-	-	
	T	$V_I = V_{CCI}$ or $GND$ , $Io = 0$	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	5	^
	$I_{CCA}$		,		-	-	2	μΑ		
			0 <b>V</b>	5.5V	ı	=	-	=	-2	
			1.2V	1.65V to 5.5V	0	2.3	5.0	-	ı	
	T	$V_I = V_{CCI}$ or	1.4V to 3.6V	1.65V to 5.5V	ı	-	-	-	5	
	$I_{CCB}$	GND, $Io = 0$	3.6V	0V	-	-	-	-	-2	μΑ
			0V	5.5V	-	-	-	-	2	
т	, T	$V_I = V_{CCI}$ or	1.2V	1.65V to 5.5V	0.0	2.4	8.0	-	-	4
1 <sub>CC</sub>	$_{\rm A} + { m I}_{ m CCB}$	GND, $Io = 0$	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	8	μΑ
		$V_I = V_{CCI}$ or	1.2V	1.65V to 5.5V	0.0	0.05	0.4	-	-	
]	I <sub>CCZA</sub>	GND, Io = 0, OE = GND	1.4V to 3.6V	1.65V to 5.5V	1	-	-	-	3	μA
	_	$V_{\rm I} = V_{\rm CCI}$ or	1.2V	1.65V to 5.5V	0.0	2.3	5.0	=	ı	
]	I <sub>CCZB</sub>	GND, Io = 0, OE = GND	1.4V to 3.6V	1.65V to 5.5V	-	-	-	-	5	μA
Ci	OE	-	1.2 to 3.6V	1.65V to 5.5V	-	2.5	-	-	3	pF
Cio	A port		1.2 to 3.6V	1.65V to 5.5V	-	5	-	-	6	pF
CIU	B port		1.2 to 3.0 v	1.03 ( 10 3.3 (	1	11	-	-	14	pı.

<sup>(1)</sup>  $V_{\text{CCI}}$  is the supply voltage associated with the input port. (2)  $V_{\text{CCO}}$  is the supply voltage associated with the output port.





### **AC Electrical Characteristics**

### **Timing Requirements**

a.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.2 \text{V}$ 

			$V_{CCB} = 1.8V$	$V_{CCB} = 2.5V$	$V_{CCB} = 3.3V$	$V_{CCB} = 5V$	Unit
			Тур.	Тур.	Тур.	Тур.	UIII
Data rate		20	20	20	20	Mbps	
$t_{\mathrm{W}}$	Pulse duration Data inputs		50	50	50	50	ns

b.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.5 \pm 0.1 \text{V}$ 

			$V_{CCB}=1$ .	$V_{CCB}$ =1.8±0.15 $V$		$V_{CCB}$ =2.5±0.2 $V$		$V_{CCB}$ =3.3±0.3V		$V_{CCB}=5\pm0.5V$	
			Min	Max	Min	Max	Min	Max	Min	Max	Unit
	Data rate		-	40	-	40	-	40	-	40	Mbps
$t_{\mathrm{W}}$	Pulse duration	Data inputs	25	-	25	-	25	-	25	-	ns

c.  $T_A = 25^{\circ}C$ ,  $V_{CCA} = 1.8 \pm 0.15V$ 

			$V_{CCB}$ =1.8±0.15V		$V_{CCB}=2.5\pm0.2V$		$V_{CCB}=3.3\pm0.3V$		$V_{CCB}=5\pm0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	Unit
	Data rate		-	60	-	60	-	60	-	60	Mbps
$t_{\mathrm{W}}$	Pulse duration	Data inputs	17	-	17	-	17	-	17	-	ns

d.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 2.5 \pm 0.2 \text{V}$ 

			$V_{CCB}$ =2.5±0.2 $V$		$V_{CCB}=3$	.3±0.3V	$V_{CCB}=$	Unit	
			Min	Max	Min	Max	Min	Max	UIIIt
	Data rate		-	100	-	100	-	100	Mbps
$t_{\mathrm{W}}$	t <sub>w</sub> Pulse duration Data inputs		10	-	10	-	10	-	ns

e.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 3.3 \pm 0.3 \,^{\circ}\text{V}$ 

			$V_{CCB}=3$	3.3±0.3V	V <sub>CCB</sub> =	Unit	
			Min	Max	Min	Max	Unit
Data rate		-	100	=	100	Mbps	
$t_{\mathrm{W}}$	10	-	10	-	10	-	ns

### **Switching Characteristics**

a.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.2 \text{V}$ 

Parameter	From	To	$V_{CCB}=1.8V$	$V_{CCB}=2.5V$	$V_{CCB}=3.3V$	$V_{CCB}=5V$	Unit
rarameter	(Input)	(Output)	Typ.	Тур.	Тур.	Тур.	UIII
4	A	В	6.9	5.7	5.3	5.5	nc
$t_{ m pd}$	В	A	7.4	6.4	6	5.8	ns
4	OE	A	0.2	0.2	0.2	0.2	
t <sub>en</sub>	OE	В	0.2	0.2	0.2	0.2	μs
4	OE	A	0.4	0.4	0.4	0.4	
$\iota_{ m dis}$	t <sub>dis</sub> OE B		0.2	0.2	0.2	0.2	μs
$t_{rA}, t_{fA}$	_	ise and fall mes	4.2	4.2	4.2	4.2	ns
$t_{rB}, t_{fB}$		ise and fall mes	2.1	1.5	1.2	1.1	ns
t <sub>SK(O)</sub>	Channel-to-channel skew		0.5	0.5	0.5	1.4	ns
Max data rate		-	20	20	20	20	Mbps





b.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.5 \pm 0.1 \text{V}$ 

Parameter	From	To	$V_{CCB}=1$ .	8±0.15V	$V_{CCB} = 2$	2.5±0.2V	$V_{CCB}=3$	.3±0.3V	$V_{CCB} =$	5±0.5V	Unit
Parameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	UIII
4	A	В	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	
$t_{ m pd}$	В	A	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	ns
+	OE	A	-	0.5	ı	0.5	-	0.5	ı	0.5	
t <sub>en</sub>	OE	В	-	0.5	ı	0.5	-	0.5	ı	0.5	μs
+	OE	A	-	0.5	ı	0.5	-	0.5	ı	0.5	
$t_{ m dis}$	OE	В	-	0.5	ı	0.5	-	0.5	ı	0.5	μs
$t_{rA}, t_{fA}$		ise and fall mes	1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
$t_{rB},t_{fB}$	-	ise and fall mes	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t <sub>SK(O)</sub>	Channel-to-channel skew		-	0.5	ı	0.5	-	0.5	ı	0.5	ns
Max data rate			40	-	40	-	40	-	40	-	Mbps

c.  $T_A = 25 \,^{\circ}\text{C}$ ,  $V_{CCA} = 1.8 \pm 0.15 \text{V}$ 

Domomoton	From	To	$V_{CCB}=1$ .	8±0.15V	$V_{CCB}=2$	.5±0.2V	$V_{CCB}=3$	.3±0.3V	$V_{CCB}=5\pm0.5V$		Unit
Parameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	UIII
4	A	В	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	ne
$t_{ m pd}$	В	A	1.5	12	1.3	8.4	1	7.6	0.9	7.1	ns
4	OE	A	-	0.3	-	0.25		0.25	-	0.25	
t <sub>en</sub>	OE	В	-	0.3	-	0.25		0.25	-	0.25	μs
4	OE	A	-	0.5	-	0.5		0.5	-	0.5	
$t_{ m dis}$	OE	В	-	0.5	-	0.5		0.5	-	0.5	μs
$t_{rA}, t_{fA}$	-	ise and fall mes	1	4.2	1	4.1	1	4.1	1	4.1	ns
$t_{rB},t_{fB}$	-	ise and fall mes	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
t <sub>SK(O)</sub>		-to-channel kew	-	0.5	-	0.5	-	0.5	-	0.5	ns
Max data rate			60	-	60	-	60	-	60	-	Mbps

### d. $T_A = 25$ °C, $V_{CCA} = 2.5 \pm 0.2$ V

Parameter	From	To	$V_{CCB}=2$	.5±0.2V	$V_{CCB}$ =3.3±0.3V		$V_{CCB}=5\pm0.5V$		Unit
rarameter	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Omt
4	A	В	1.1	6.3	1.0	5.2	0.9	4.7	
$t_{ m pd}$	В	A	1.2	6.6	1.1	5.1	0.9	4.4	ns
4	OE	A	-	0.25	-	0.2	-	0.2	
$t_{\rm en}$	OE	В	-	0.25	-	0.2	-	0.2	μs
4	OE	A	-	0.5	-	0.4	-	035	
$t_{ m dis}$	OE	В	-	0.5	-	0.4	-	0.35	μs
$t_{rA}, t_{fA}$	A-port rise ar	nd fall times	0.8	3.0	0.8	3.0	0.8	3.0	ns
$t_{rB}, t_{fB}$	B-port rise ar	nd fall times	0.7	3.0	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$	Channel-to-cl	nannel skew	-	0.5	=	0.5	-	0.5	ns
Max data rate		•	100	-	100	-	100	-	Mbps





e.  $T_A = 25^{\circ}C$ ,  $V_{CCA} = 3.3 \pm 0.3V$ 

Davamatan	From	To	$V_{CCB}=3$	.3±0.3V	$V_{CCB}=$	Unit	
Parameter	(Input)	(Output)	Min	Min Max			Max
+	A	В	0.9	4.7	0.8	4.0	nc
$t_{ m pd}$	В	A	1.0	4.9	0.9	3.8	ns
+	OE	A	-	0.2	-	0.2	
t <sub>en</sub>	OE	В	-	0.2	-	0.2	μs
4	OE	A	-	0.3	-	0.3	
$t_{ m dis}$	OE	В	-	0.3	-	0.3	μs
$t_{rA}, t_{fA}$	A-port rise and	d fall times	0.7	2.8	0.7	2.8	ns
$t_{rB}, t_{fB}$	B-port rise and	d fall times	0.5	2.7	0.4	2.7	ns
$t_{SK(O)}$	Channel-to-ch	annel skew	-	0.5	ı	0.5	ns
Max data rate			100	-	100	-	Mbps

**Operating Characteristics** 

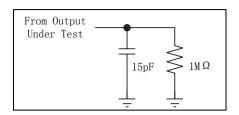
operating enaracteristics											
			$ m V_{CCA}$								
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V		
			$ m V_{CCB}$								
Parameter		<b>Test Conditions</b>							3.3V	Unit	
			5V	1.8V	1.8V	1.8V	2.5V	5V	to		
		_							5.5V		
			Тур.	Тур.	Typ.	Typ.	Тур.	Тур.	Тур.		
C	A-port input, B-port output.	$C_L=0$ , $f=10$ MHz,	7.8	10	9	8	8	8	9		
$C_{pdA}$	B-port input, A-port output.	$tr = t_f = 1ns,$	12	11	11	11	11	11	11		
C	A-port input, B-port output.	$OE=V_{CCA}$	38.1	28	28	28	29	30	30		
$C_{pdB}$	B-port input, A-port output.	(outputs enabled)	25.4	18	18	18	18	21	21	nE	
C	A-port input, B-port output.	$C_L=0, f=10 \text{ MHz},$	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF	
$C_{pdA}$	B-port input, A-port output.	$tr = t_f = 1ns,$	0.01	0.01	0.01	0.01	0.01	0.01	0.01		
C	A-port input, B-port output.	OE=GND	0.01	0.01	0.01	0.01	0.01	0.01	0.03		
$C_{pdB}$	B-port input, A-port output.	(outputs disabled)	0.01	0.01	0.01	0.01	0.01	0.02	0.04		



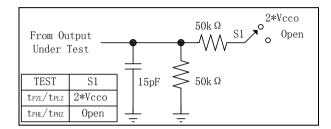


### **Test Circuit**

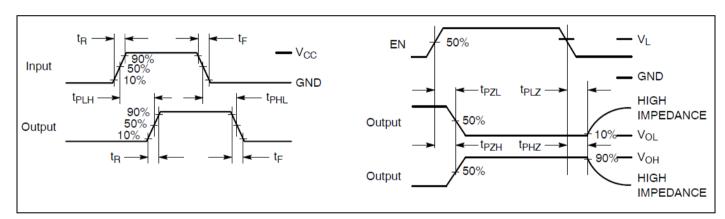
1> Load circuit for Max data rate, pulse duration propagation delay output rise and fall time measurement



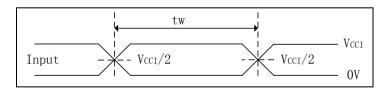
2> Load circuit for enable/disable time measurement



3> Timing Definitions for Propagation Delays and Enable/Disable Measurement



4> Voltage waveforms pulse duration



- 5> Notes
- A. C<sub>L</sub> includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR\_10 MHz,  $Z_0 = 50$  W,  $dv/dt \ge 1$  V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as tpd.
- E.  $V_{\text{CCI}}$  is the  $V_{\text{CC}}$  associated with the input port.
- F.  $V_{\text{CCO}}$  is the  $V_{\text{CC}}$  associated with the output port.
- G. All parameters and waveforms are not applicable to all devices.





### **Principles of Operation**

### **Applications**

The PI4ULS5V102 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

#### Architecture

The PI4ULS5V102 architecture (*see Figure1*) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the PI4ULS5V102 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one shots detects rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70  $\Omega$  at  $V_{CCO}=1.2$  V to 1.8 V, 50  $\Omega$  at  $V_{CCO}=1.8$  V to 3.3 V, and 40  $\Omega$  at  $V_{CCO}=3.3$  V to 5 V.

#### **Input Driver Requirements**

Typical  $I_{IN}$  vs  $V_{IN}$  characteristics of the PI4ULS5V102 are shown in *Figure 2*. For proper operation, the device driving the data I/Os of the PI4ULS5V102 must have drive strength of at least  $\pm 2$ mA.

### Power Up

During operation, ensure that  $V_{CCA} \le V_{CCB}$  at all times. During power-up sequencing,  $VCCA \ge VCCB$  does not damage the device, so any power supply can be ramped up first. The PI4ULS5V102 has circuitry that disables all output ports when either  $V_{CC}$  is switched off  $(V_{CCA/B} = 0 \text{ V})$ .

### **Enable and Disable**

The PI4ULS5V102 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time ( $t_{dis}$ ) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (ten) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

#### Pull-up or Pull-down Resistors on I/O Lines

The PI4ULS5V102 is designed to drive capacitive loads of up to 70 pF. The output drivers of the PI4ULS5V102 have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 k $\Omega$  to ensure that they do not contend with the output drivers of the PI4ULS5V102.

For the same reason, the PI4ULS5V102 should not be used in applications such as I2C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O.



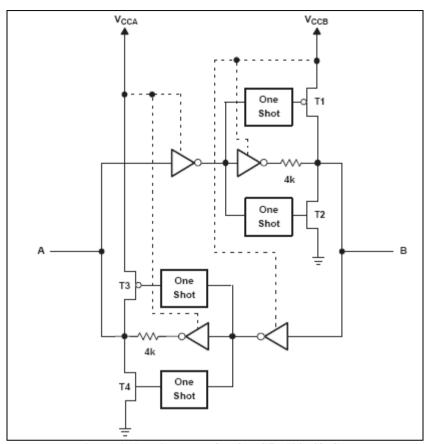


Figure 1. Architecture of PI4ULS5V102 I/O Cell

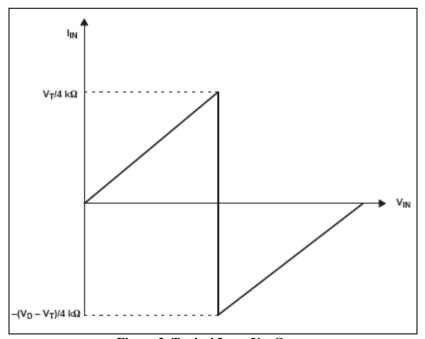


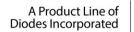
Figure 2. Typical I<sub>IN</sub> vs V<sub>IN</sub> Curve

#### Note:

A. VT is the input threshold voltage of the PI4ULS5V102 (typically  $V_{\text{\tiny CCI}}/2).$ 

B. VD is the supply voltage of the external driver.





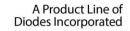


### **Part Marking**



1st Y: Die Rev 2nd Y: Date Code (Year) W: Date Code (Workweek) 1st X: Assembly Site Code 2nd X: Fab Site Code Bar above fab code means Cu wire Bar above "S" means Fab3 of MGN

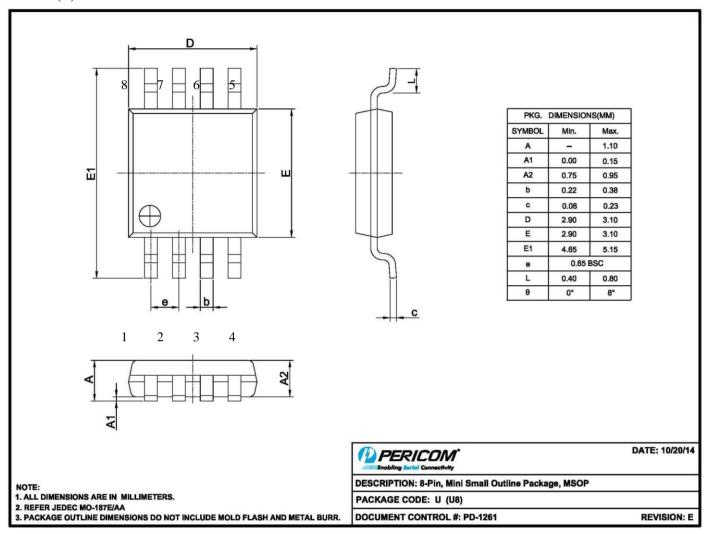






### **Packaging Mechanical**

8-MSOP (U)



#### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

### **Ordering Information**

Part Number	Package Code	Package Description
PI4ULS5V102UEX	U	8-Pin, Mini Small Outline Package (MSOP)

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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